

### 1. General description

The 74HC00; 74HCT00 is a quad 2-input NAND gate. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of  $V_{CC}$ .

### 2. Features and benefits

- Wide supply voltage range from 2.0 V to 6.0 V
- CMOS low power dissipation
- High noise immunity
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Input levels:
  - For 74HC00: CMOS level
  - For 74HCT00: TTL level
- Complies with JEDEC standards:
  - JESD8C (2.7 V to 3.6 V)
  - JESD7A (2.0 V to 6.0 V)
- ESD protection:
  - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
  - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

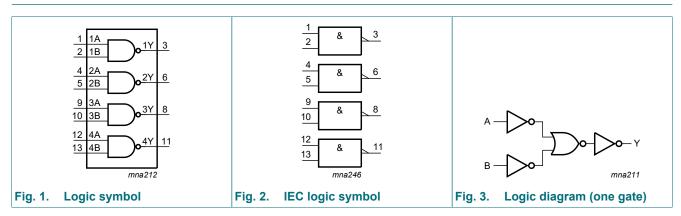
### 3. Ordering information

#### Table 1. Ordering information

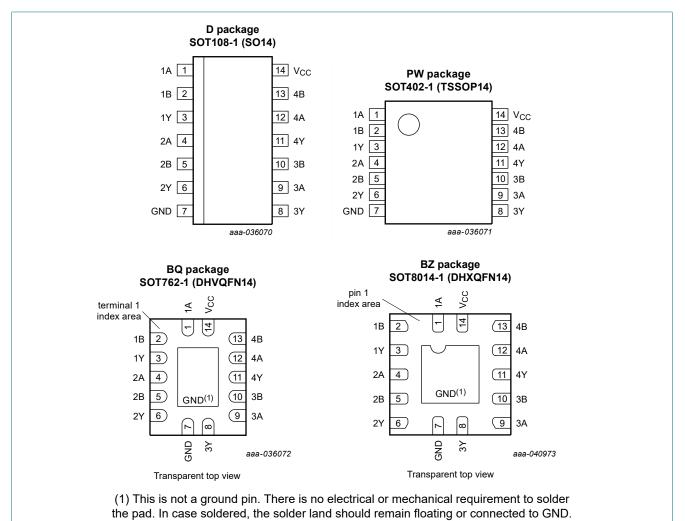
Type number	Package			
	Temperature range	Name	Description	Version
74HC00D 74HCT00D	-40 °C to +125 °C	SO14	plastic small outline package; 14 leads; body width 3.9 mm	<u>SOT108-1</u>
74HC00PW 74HCT00PW	-40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package; 14 leads; body width 4.4 mm	<u>SOT402-1</u>
74HC00BQ 74HCT00BQ	-40 °C to +125 °C	DHVQFN14	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 × 3 × 0.85 mm	<u>SOT762-1</u>
74HC00BZ 74HCT00BZ	-40 °C to +125 °C	DHXQFN14	plastic, leadless dual in-line compatible thermal enhanced extreme thin quad flat package; no leads; 14 terminals; 0.4 mm pitch; body 2 mm × 2 mm × 0.48 mm	<u>SOT8014-1</u>

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### 4. Functional diagram



### 5. Pinning information



### 5.1. Pinning

74HC\_HCT00

### 5.2. Pin description

Table 2. Pin description						
Symbol	Pin	Description				
1A, 2A, 3A, 4A	1, 4, 9, 12	data input				
1B, 2B, 3B, 4B	2, 5, 10, 13	data input				
1Y, 2Y, 3Y, 4Y	3, 6, 8, 11	data output				
GND	7	ground (0 V)				
V <sub>CC</sub>	14	supply voltage				

### 6. Functional description

#### Table 3. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care.

Input	Output	
nA	nB	nY
L	X	Н
Х	L	Н
Н	Н	L

### 7. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+7	V
I <sub>IK</sub>	input clamping current	$V_{\rm I}$ < -0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V	[1]	-	±20	mA
I <sub>OK</sub>	output clamping current	$V_{\rm O}$ < -0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	[1]	-	±20	mA
lo	output current	-0.5 V < V <sub>O</sub> < V <sub>CC</sub> + 0.5 V		-	±25	mA
I <sub>CC</sub>	supply current			-	50	mA
I <sub>GND</sub>	ground current			-50	-	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to +125 °C				
		SOT108-1 (SO14) SOT402-1 (TSSOP14) SOT762-1 (DHVQFN14)	[2]	-	500	mW
		SOT8014-1 (DHXQFN14)	[3]	-	250	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

- [2] For SOT108-1 (SO14) package: P<sub>tot</sub> derates linearly with 10.1 mW/K above 100 °C. For SOT402-1 (TSSOP14) package: P<sub>tot</sub> derates linearly with 7.3 mW/K above 81 °C.
- For SOT762-1 (DHVQFN14) package: Ptot derates linearly with 9.6 mW/K above 98 °C.

[3] For SOT8014-1 (DHXQFN14) package: Ptot derates linearly with 8.7 mW/K above 121 °C.

### 8. Recommended operating conditions

#### Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions		74HC00		74HCT00			Unit
			Min	Тур	Мах	Min	Тур	Max	
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
Vo	output voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 2.0 V	-	-	625	-	-	-	ns/V
		V <sub>CC</sub> = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V <sub>CC</sub> = 6.0 V	-	-	83	-	-	-	ns/V

### 9. Static characteristics

#### Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Мах	Min	Max	1
74HC00										
V <sub>IH</sub>	HIGH-level	V <sub>CC</sub> = 2.0 V	-	1.2	-	1.5	-	1.5	-	V
	input voltage	V <sub>CC</sub> = 4.5 V	-	2.4	-	3.15	-	3.15	-	V
		V <sub>CC</sub> = 6.0 V	-	3.2	-	4.2	-	4.2	-	V
VIL	LOW-level	V <sub>CC</sub> = 2.0 V	-	0.8	-	-	0.5	-	0.5	V
	input voltage	V <sub>CC</sub> = 4.5 V	-	2.1	-	-	1.35	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	-	-	1.8	-	1.8	V
V <sub>OH</sub>	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V	-	2.0	-	1.9	-	1.9	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V	-	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V	-	6.0	-	5.9	-	5.9	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 4.5 V	-	4.32	-	3.84	-	3.7	-	V
		I <sub>O</sub> = -5.2 mA; V <sub>CC</sub> = 6.0 V	-	5.81	-	5.34	-	5.2	-	V
V <sub>OL</sub>	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V	-	0	-	-	0.1	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	0	-	-	0.1	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V	-	0	-	-	0.1	-	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	0.15	-	-	0.33	-	0.4	V
		I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 6.0 V	-	0.16	-	-	0.33	-	0.4	V
I	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0$ V	-	-	-	-	±1	-	±1	μA
I <sub>CC</sub>	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0$ V	-	-	-	-	20	-	40	μA
CI	input capacitance		-	3.5	-	-	-	-	-	pF

#### **Quad 2-input NAND gate**

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Мах	Min	Max	
74HCT0	0	,							•	
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	1.6	-	2.0	-	2.0	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	1.2	-	-	0.8	-	0.8	V
V <sub>OH</sub>	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I <sub>O</sub> = -20 μA	-	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = -4.0 mA	-	4.32	-	3.84	-	3.7	-	V
V <sub>OL</sub>	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I <sub>O</sub> = 20 μA	-	0	-	-	0.1	-	0.1	V
		I <sub>O</sub> = 4 mA	-	0.15	-	-	0.33	-	0.4	V
l <sub>l</sub>	input leakage current	$V_1 = V_{CC}$ or GND; $V_{CC} = 6.0$ V	-	-	-	-	±1	-	±1	μA
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0$ V	-	-	-	-	20	-	40	μA
ΔI <sub>CC</sub>	additional supply current	per input pin; $V_1 = V_{CC} - 2.1 \text{ V}; I_0 = 0 \text{ A};$ other inputs at $V_{CC}$ or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V	-	150	-	-	675	-	735	μA
CI	input capacitance		-	3.5	-	-	-	-	-	pF

### **10.** Dynamic characteristics

### Table 7. Dynamic characteristics

GND = 0 V;  $C_L = 50 pF$ ; for test circuit see Fig. 5.

Symbol	Parameter	Conditions			25 °C		-40 °C t	o +85 °C	-40 °C to	o +125 °C	Unit
				Min	Тур	Мах	Min	Max	Min	Max	
74HC00		L									
t <sub>pd</sub>	t <sub>pd</sub> propagation delay	nA, nB to nY; see Fig. 4	[1]								
		V <sub>CC</sub> = 2.0 V		-	25	-	-	115	-	135	ns
		V <sub>CC</sub> = 4.5 V		-	9	-	-	23	-	27	ns
	V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF		-	7	-	-	-	-	-	ns	
		V <sub>CC</sub> = 6.0 V		-	7	-	-	20	-	23	ns
t <sub>t</sub>	transition	see Fig. 4	[2]								
	time	V <sub>CC</sub> = 2.0 V		-	19	-	-	95	-	110	ns
		V <sub>CC</sub> = 4.5 V		-	7	-	-	19	-	22	ns
		V <sub>CC</sub> = 6.0 V		-	6	-	-	16	-	19	ns
C <sub>PD</sub>	power dissipation capacitance	per package; V <sub>I</sub> = GND to V <sub>CC</sub>	[3]	-	22	-	-	-	-	-	pF

#### **Quad 2-input NAND gate**

Symbol	Parameter	Conditions	25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit	
			Min	Тур	Мах	Min	Max	Min	Мах	
74HCT0	0									
t <sub>pd</sub>	propagation	nA, nB to nY; see Fig. 4 [1]								
	delay	V <sub>CC</sub> = 4.5 V	-	12	-	-	24	-	29	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	10	-	-	-	-	-	ns
t <sub>t</sub>	transition time	$V_{CC} = 4.5 V; \text{ see } Fig. 4$ [2]	-	-	-	-	29	-	22	ns
C <sub>PD</sub>	power dissipation capacitance	per package; [3] $V_{I}$ = GND to $V_{CC}$ - 1.5 V	-	22	-	-	-	-	-	pF

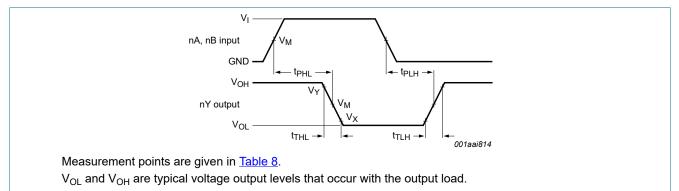
[1]  $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .

[2]  $t_t$  is the same as  $t_{THL}$  and  $t_{TLH}$ . [3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ):  $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:  $f_i$  = input frequency in MHz;  $f_o$  = output frequency in MHz;  $C_L$  = output load capacitance in pF; V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma (C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$ 

### 10.1. Waveforms and test circuit

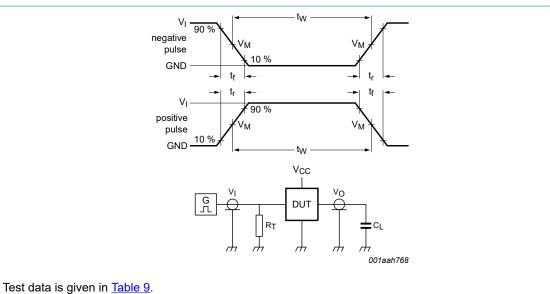


#### Input to output propagation delays Fig. 4.

#### **Table 8. Measurement points**

Туре	Input	Output				
	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>		
74HC00	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>	0.1V <sub>CC</sub>	0.9V <sub>CC</sub>		
74HCT00	1.3 V	1.3 V	0.1V <sub>CC</sub>	0.9V <sub>CC</sub>		

#### **Quad 2-input NAND gate**



Definitions test circuit:

 $R_T$  = termination resistance should be equal to output impedance  $Z_o$  of the pulse generator;

 $C_L$  = load capacitance including jig and probe capacitance.

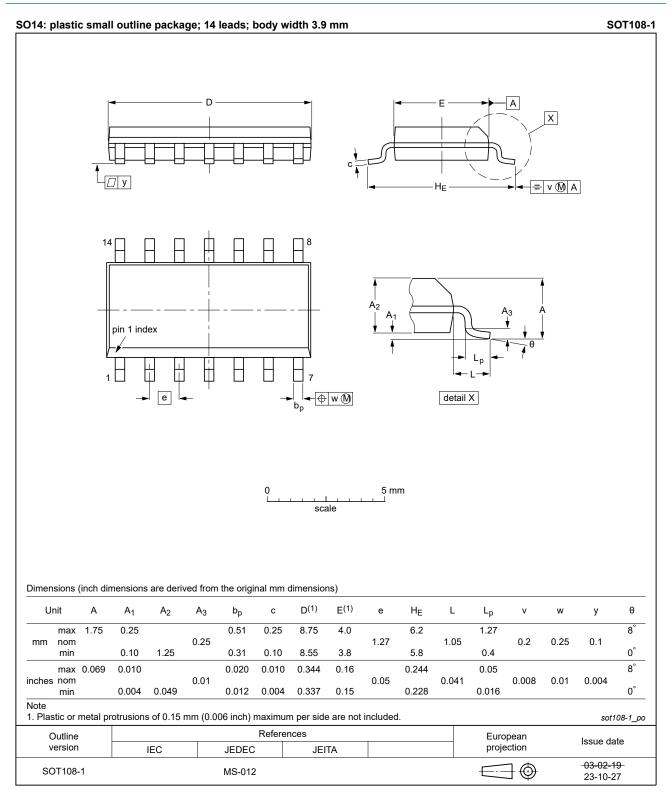
#### Fig. 5. Test circuit for measuring switching times

#### Table 9. Test data

Туре	Input L		Load	Test	
	VI	t <sub>r</sub> , t <sub>f</sub>	CL		
74HC00	V <sub>CC</sub>	6.0 ns	15 pF, 50 pF	t <sub>PLH</sub> , t <sub>PHL</sub>	
74HCT00	3.0 V	6.0 ns	15 pF, 50 pF	t <sub>PLH</sub> , t <sub>PHL</sub>	

#### **Quad 2-input NAND gate**

### **11. Package outline**



#### Fig. 6. Package outline SOT108-1 (SO14)

#### **Quad 2-input NAND gate**

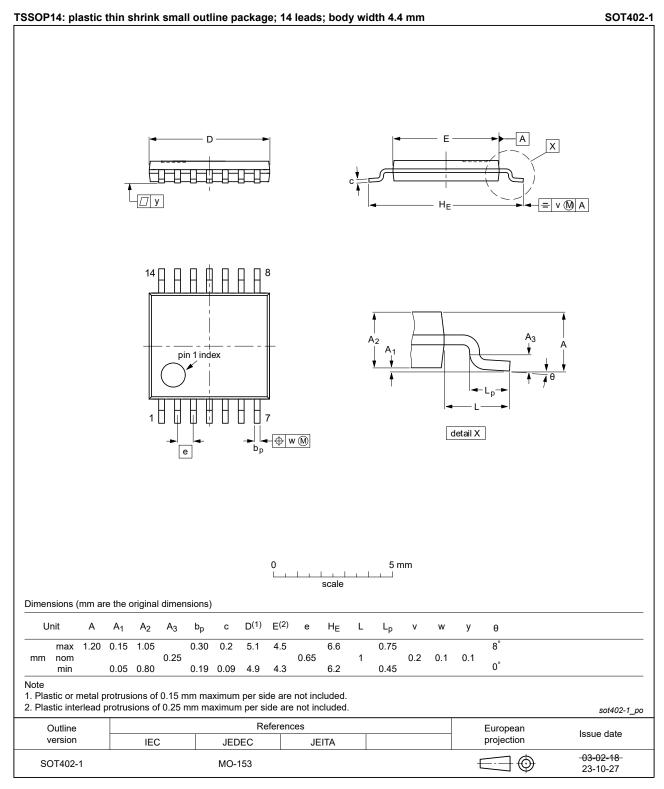


Fig. 7. Package outline SOT402-1 (TSSOP14)

### **Quad 2-input NAND gate**

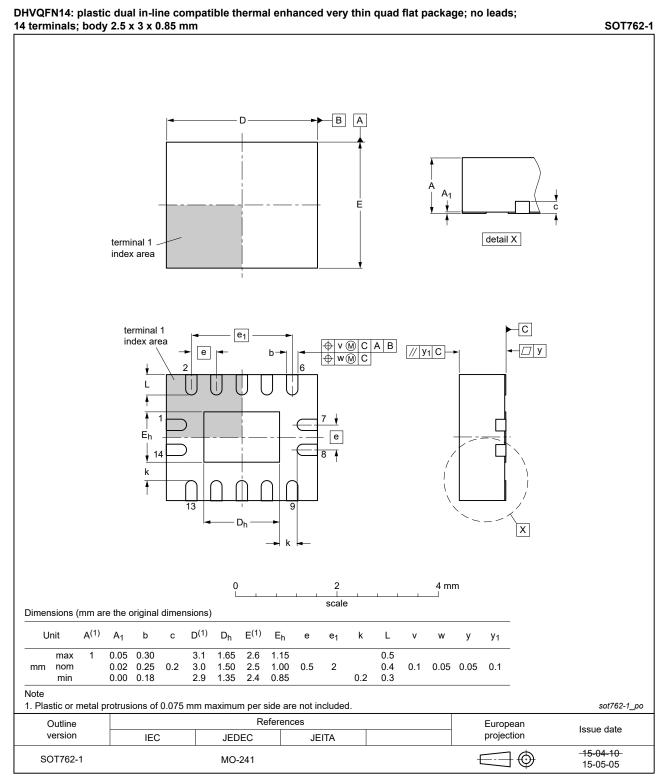
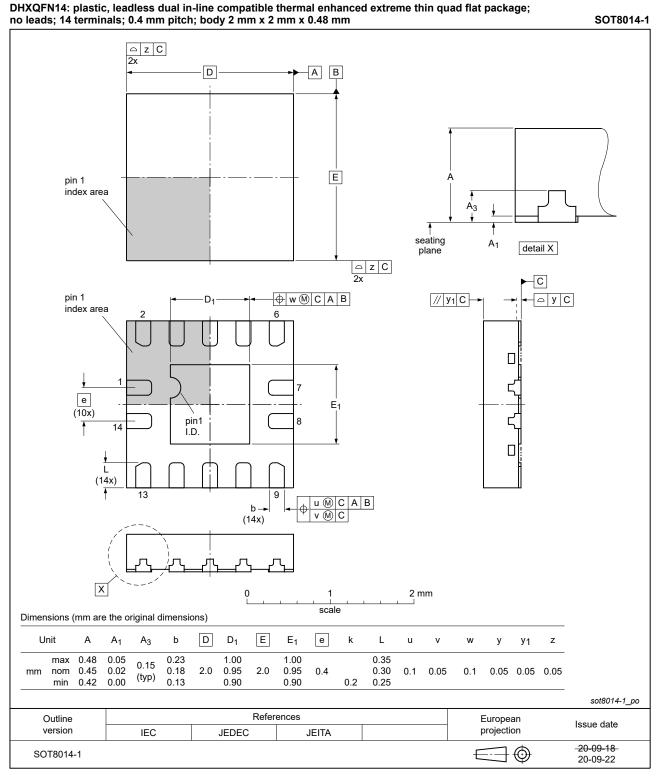


Fig. 8. Package outline SOT762-1 (DHVQFN14)

### **Quad 2-input NAND gate**





### 12. Abbreviations

Table 10. Abbreviation	Table 10. Abbreviations						
Acronym	Description						
ANSI	American National Standards Institute						
CDM	Charged Device Model						
CMOS	Complementary Metal-Oxide Semiconductor						
DUT	Device Under Test						
ESD	ElectroStatic Discharge						
ESDA	ElectroStatic Discharge Association						
НВМ	Human Body Model						
JEDEC	Joint Electron Device Engineering Council						
TTL	Transistor-Transistor Logic						

# 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74HC_HCT00 v.11	20250429	Product data sheet	-	74HC_HCT00 v.10		
Modifications:	• Type numbers 74HC00BZ and 74HCT00BZ (SOT8014-1/DHXQFN14) added.					
74HC_HCT00 v.10	20240215	Product data sheet	-	74HC_HCT00 v.9		
Modifications:		<ul> <li>Fig. 6, Fig. 7: Aligned SO and TSSOP package outline drawings to JEDEC MS-012 and</li> </ul>				
74HC_HCT00 v.9	20211022	Product data sheet	-	74HC_HCT00 v.8		
Modifications:	• <u>Section 9</u> : \	<u>Section 9</u> : V <sub>OL</sub> condition for 74HCT00 corrected. (Errata)				
74HC_HCT00 v.8	20210810	Product data sheet	-	74HC_HCT00 v.7		
Modifications:	guidelines c Legal texts Type number <u>Section 2</u> u	<ul> <li>Type numbers 74HC00DB and 74HCT00DB (SOT337-1/SSOP14) removed.</li> </ul>				
74HC_HCT00 v.7	20151125	Product data sheet	-	74HC_HCT00 v.6		
Modifications:	Type numbers 74HC00N and 74HCT00N (SOT27-1) removed.					
74HC_HCT00 v.6	20111214	Product data sheet	-	74HC_HCT00 v.5		
Modifications:	Legal pages updated.					
74HC_HCT00 v.5	20101125	Product data sheet	-	74HC_HCT00 v.4		
74HC_HCT00 v.4	20100111	Product data sheet	-	74HC_HCT00 v.3		
74HC_HCT00 v.3	20030630	Product data sheet	-	74HC_HCT00_CNV v.2		
74HC_HCT00_CNV v.2	19970826	Product specification	-	-		

### 14. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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#### **Quad 2-input NAND gate**

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